

N-Channel Power MOSFET

800V, 0.3A, 21.6Ω

FEATURES

- Advanced planar process
- 100% avalanche tested
- Fast switching

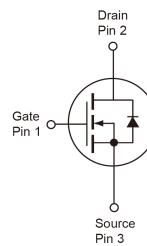
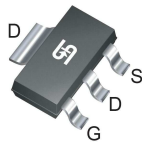
APPLICATION

- Power Supply
- Lighting

| KEY PERFORMANCE PARAMETERS | | |
|----------------------------|-------|------|
| PARAMETER | VALUE | UNIT |
| V_{DS} | 800 | V |
| $R_{DS(on)}$ (max) | 21.6 | Ω |
| Q_g | 5 | nC |



SOT-223



Notes: Moisture sensitivity level: level 3. Per J-STD-020

| ABSOLUTE MAXIMUM RATINGS ($T_A = 25^\circ\text{C}$ unless otherwise noted) | | | |
|-----------------------------------------------------------------------------|----------------|--------------|------|
| PARAMETER | SYMBOL | LIMIT | UNIT |
| Drain-Source Voltage | V_{DS} | 800 | V |
| Gate-Source Voltage | V_{GS} | ±30 | V |
| Continuous Drain Current | I_D | 0.3 | A |
| Pulsed Drain Current ^(Note 1) | I_{DM} | 1 | A |
| Single Pulse Avalanche Energy ^(Note 2) | E_{AS} | 90 | mJ |
| Avalanche Current, Repetitive or Not-Repetitive ^(Note 1) | I_{AR} | 1 | A |
| Total Power Dissipation @ $T_C = 25^\circ\text{C}$ | P_{DTOT} | 2.1 | W |
| Operating Junction Temperature | T_J | 150 | °C |
| Operating Junction and Storage Temperature Range | T_J, T_{STG} | - 55 to +150 | °C |

| THERMAL PERFORMANCE | | | |
|----------------------------------------|-----------------|-------|------|
| PARAMETER | SYMBOL | LIMIT | UNIT |
| Junction to Ambient Thermal Resistance | $R_{\theta JA}$ | 60 | °C/W |

Notes: $R_{\theta JA}$ is the sum of the junction-to-case and case-to-ambient thermal resistances. The case thermal reference is defined at the solder mounting surface of the drain pins. $R_{\theta JA}$ is guaranteed by design while $R_{\theta CA}$ is determined by the user's board design. $R_{\theta JA}$ shown below for single device operation on FR-4 PCB in still air

| ELECTRICAL SPECIFICATIONS ($T_A = 25^\circ\text{C}$ unless otherwise noted) | | | | | | |
|-------------------------------------------------------------------------------------|-------------------------------------------------------------------------------------|--------------|-----|------|----------|---------------|
| PARAMETER | CONDITIONS | SYMBOL | MIN | TYP | MAX | UNIT |
| Static | | | | | | |
| Drain-Source Breakdown Voltage | $V_{GS} = 0\text{V}, I_D = 1\text{mA}$ | BV_{DSS} | 800 | -- | -- | V |
| Drain-Source On-State Resistance | $V_{GS} = 10\text{V}, I_D = 0.15\text{A}$ | $R_{DS(ON)}$ | -- | 18 | 21.6 | Ω |
| Gate Threshold Voltage | $V_{DS} = V_{GS}, I_D = 250\mu\text{A}$ | $V_{GS(TH)}$ | 3 | -- | 5 | V |
| Zero Gate Voltage Drain Current | $V_{DS} = 800\text{V}, V_{GS} = 0\text{V}$ | I_{DSS} | -- | -- | 25 | μA |
| Gate Body Leakage | $V_{GS} = \pm 30\text{V}, V_{DS} = 0\text{V}$ | I_{GSS} | -- | -- | ± 10 | μA |
| Forward Transconductance | $V_{DS} = 40\text{V}, I_D = 0.1\text{A}$ | g_{fs} | -- | 0.36 | -- | S |
| Diode Forward Voltage | $I_S = 0.2\text{A}, V_{GS} = 0\text{V}$ | V_{SD} | -- | -- | 1.4 | V |
| Dynamic (Note 3) | | | | | | |
| Total Gate Charge | $V_{DS} = 640\text{V}, I_D = 0.3\text{A},$ $V_{GS} = 10\text{V}$ | Q_g | -- | 5 | 6 | nC |
| Gate-Source Charge | | Q_{gs} | -- | 1 | -- | |
| Gate-Drain Charge | | Q_{gd} | -- | 2 | -- | |
| Input Capacitance | $V_{DS} = 25\text{V}, V_{GS} = 0\text{V},$ $f = 1.0\text{MHz}$ | C_{iss} | -- | 155 | 200 | pF |
| Output Capacitance | | C_{oss} | -- | 20 | 26 | |
| Reverse Transfer Capacitance | | C_{rss} | -- | 2.7 | 4 | |
| Switching (Note 4) | | | | | | |
| Turn-On Delay Time | $V_{GS} = 10\text{V}, I_D = 0.3\text{A},$ $V_{DS} = 400\text{V}, R_G = 25\Omega$ | $t_{d(on)}$ | -- | 10 | 30 | ns |
| Turn-On Rise Time | | t_r | -- | 20 | 50 | |
| Turn-Off Delay Time | | $t_{d(off)}$ | -- | 16 | 45 | |
| Turn-Off Fall Time | | t_f | -- | 25 | 60 | |

Note:

1. Pulse test: pulse width $\leq 300\mu\text{s}$, duty cycle $\leq 2\%$
2. ($V_{DD} = 50\text{V}, I_{AS} = 0.8\text{A}, L = 170\text{mH}, R_G = 25\Omega$)
3. For design reference only, not subject to production testing.
4. Switching time is essentially independent of operating temperature.

ORDERING INFORMATION

| PART NO. | PACKAGE | PACKING |
|-----------------|----------------|---------------------|
| TSM1N80CW RPG | SOT-223 | 2,500pcs / 13" Reel |

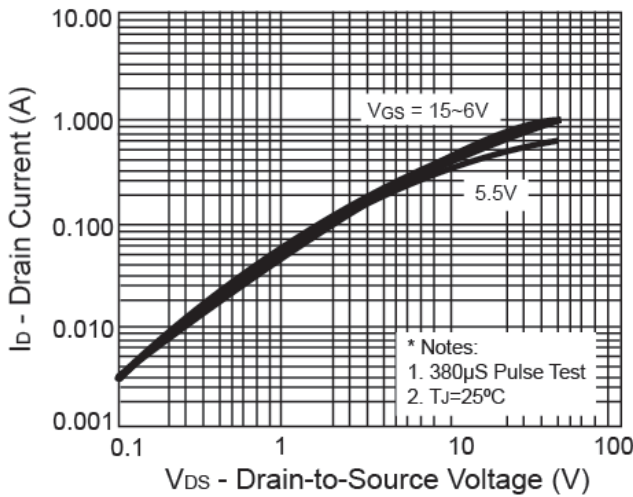
Note:

1. Compliant to RoHS Directive 2011/65/EU and in accordance to WEEE 2002/96/EC
2. Halogen-free according to IEC 61249-2-21 definition

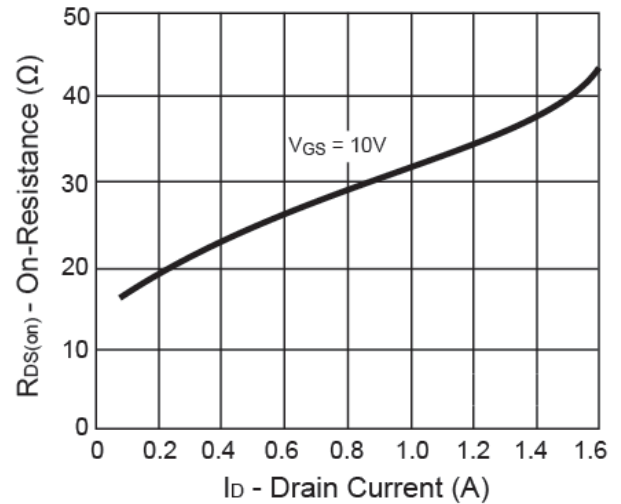
CHARACTERISTICS CURVES

($T_A = 25^\circ\text{C}$ unless otherwise noted)

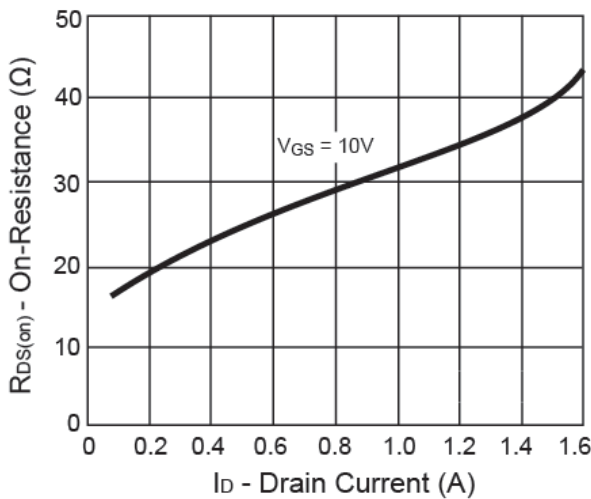
Output Characteristics



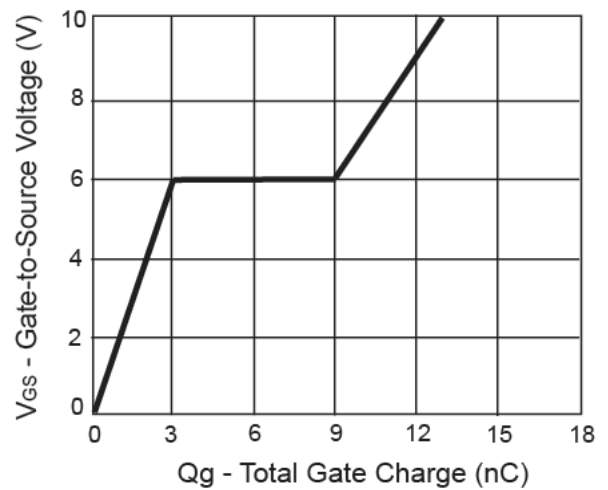
Transfer Characteristics



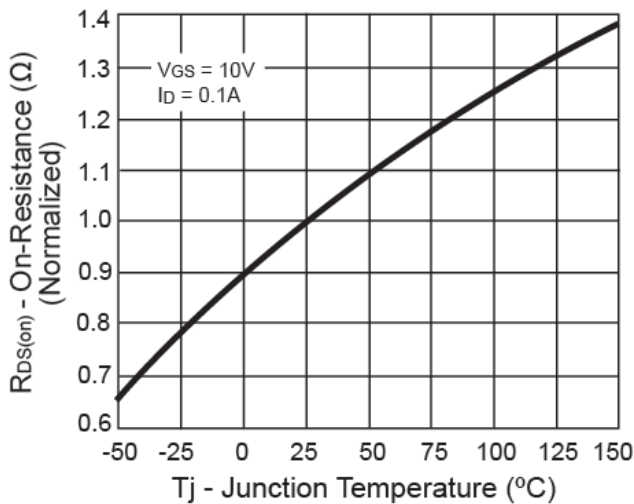
On-Resistance vs. Drain Current



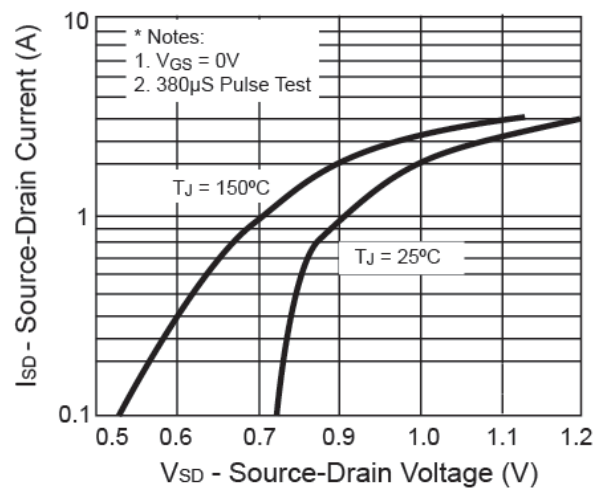
Gate Charge



On-Resistance vs. Junction Temperature



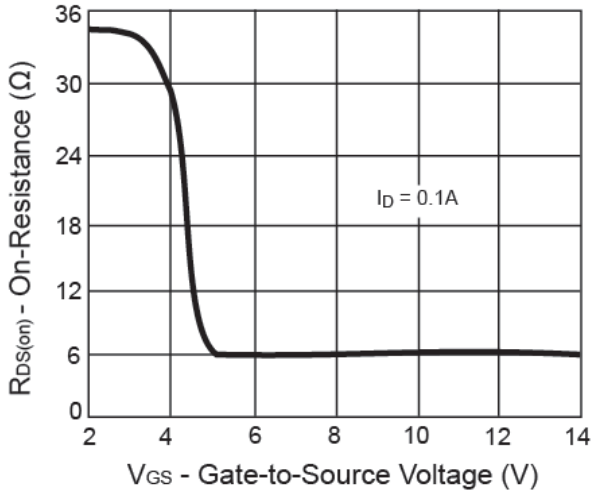
Source-Drain Diode Forward Voltage



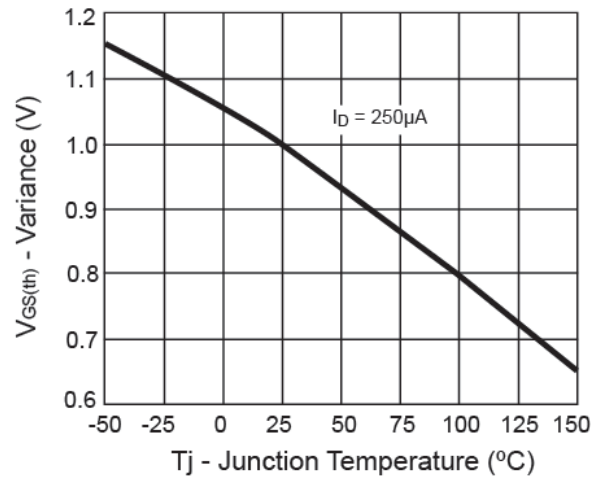
CHARACTERISTICS CURVES

($T_A = 25^\circ\text{C}$ unless otherwise noted)

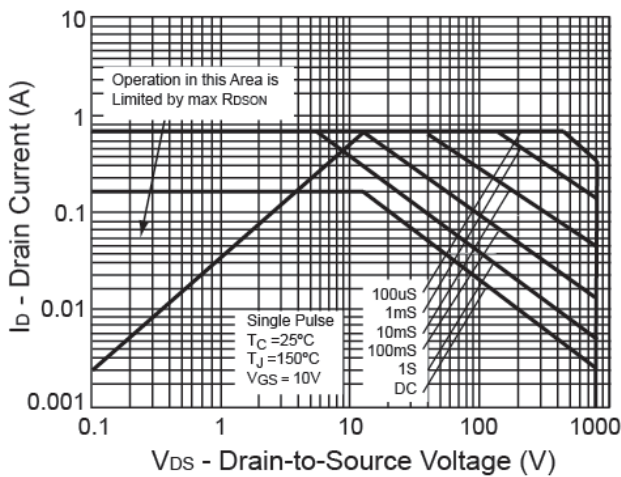
On-Resistance vs. Gate-Source Voltage



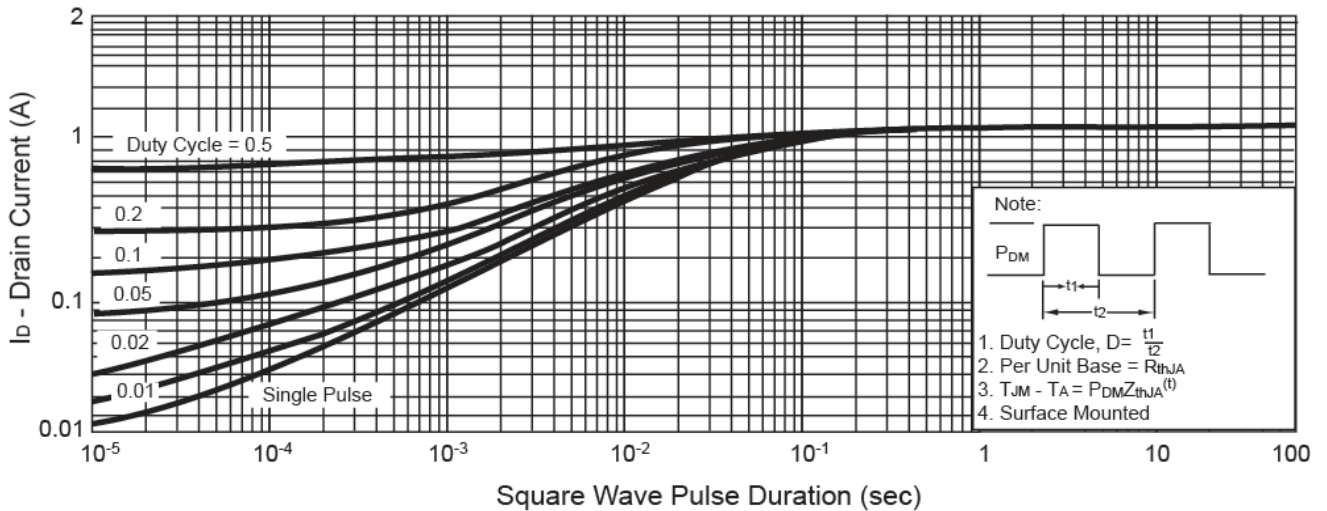
Threshold Voltage



Maximum Safe Operating Area

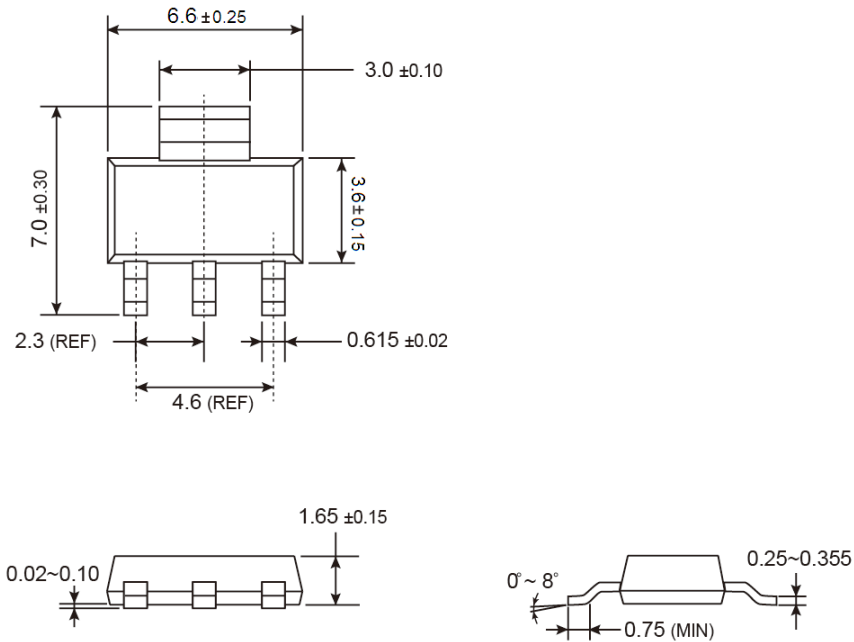


Normalized Thermal Transient Impedance, Junction-to-Ambient

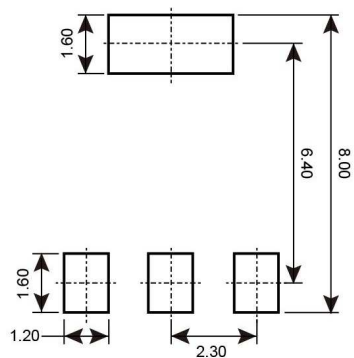


PACKAGE OUTLINE DIMENSIONS (Unit: Millimeters)

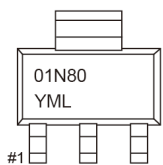
SOT-223



SUGGESTED PAD LAYOUT (Unit: Millimeters)



MARKING DIAGRAM



Y = Year Code
M = Month Code for Halogen Free Product
O =Jan **P** =Feb **Q** =Mar **R** =Apr
S =May **T** =Jun **U** =Jul **V** =Aug
W =Sep **X** =Oct **Y** =Nov **Z** =Dec
L = Lot Code (1~9, A~Z)

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